

Abstract Submitted
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Shot Noise in Single-Molecule Transistors ZACHARY KEANE,
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vices have been studied extensively, both experimentally and theoretically, a de-
tailed understanding of the physics of charge transport through molecules is still
lacking. Recent experiments have shown that it is feasible to measure shot noise
in mechanically fabricated single-molecule transistors. Shot noise is a particularly
interesting measurement in that it has the potential to reveal details about the cor-
relations between electrons as they cross a molecule. In devices known to exhibit
strong correlated-electron effects (e.g. in the Kondo regime), shot noise measure-
ments could provide useful guidance to theorists as they attempt to develop working
models for electron transport. We present preliminary results of noise measurements
in three-terminal single-molecule devices fabricated by electromigration.

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